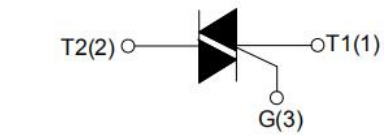
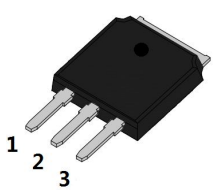
BTA08/BTB08 Series 8A Triacs

DESCRIPTION:

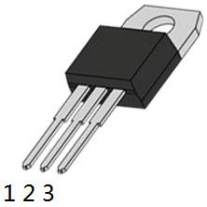
With high ability to withstand the shock loading of Large current, BTA08/BTB08 series triacs provide high dv/dt rate with strong resistance to electromagnetic interface. With high commutation performances, 3 quadrants products especially recommended for use on inductive load. From all three terminals to external heatsink, BTA08 provides a rated insulation voltage of 2500 V_{RMS} complying with UL standards (File ref: E516503).



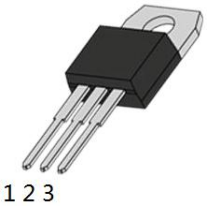


TO-251-4R

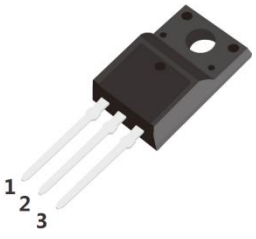
TO-252-4R



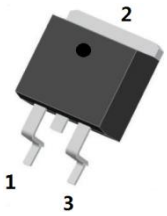
TO-220A（Ins ）



TO-220B
（Non-Ins ）



TO-220F（Ins）



TO-263

MAIN FEATURES:

symbol	value	unit
$I_{T(RMS)}$	8	A
V_{DRM}/V_{RRM}	600/800	V
V_{TM}	≤1.5	V

ABSOLUTE MAXIMUM RATINGS:

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40~150	℃
Operating junction temperature range	T_j	-40~125	℃
Repetitive peak off-state voltage (T_j=25℃)	V_{DRM}	600/800	V
Repetitive peak reverse voltage (T_j=25℃)	V_{RRM}	600/800	V
RMS on-state current	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I_{TSM}	80	A

I^2t value for fusing (t_p=10ms)	I^2t	32	A^2s
Critical rate of rise of on-state current(I_G=2×I_{GT})	dI/dt	50	A/μs
Peak gate current	I_{GM}	4	A
Average gate power dissipation	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	5	W

ELECTRICAL CHARACTERISTICS (T_j=25℃ unless otherwise specified)

3 Quadrants：

Parameter	Test Condition	Quadrant		Value				Unit
				TW	SW	CW	BW	
I_{GT}	V_D=12V, R_L=33Ω	Ⅰ-Ⅱ-Ⅲ	MAX	5	10	35	50	mA
V_{GT}				1.5				V
V_{GD}	V_D=V_{DRM}	Ⅰ-Ⅱ-Ⅲ	MIN	0.2				V
I_H	I_T=100mA		MAX	10	20	40	60	mA
I_L	I_G=1.2I_{GT}	Ⅰ-Ⅲ	MAX	20	25	50	70	mA
		Ⅱ		25	35	70	90	
dV/dt	V_D=2/3V_{DRM} T_j=125℃ Gate open		MIN	50	200	500	1000	V/μs

4 Quadrants：

Parameter	Test Condition	Quadrant		Value		Unit
				C	B	
I_{GT}	V_D=12V, R_L=33Ω	Ⅰ-Ⅱ-Ⅲ	MAX	25	50	mA
		Ⅳ		50	70	mA
V_{GT}		ALL		1.5		V
V_{GD}	V_D=V_{DRM}	ALL	MIN	0.2		V
I_H	I_T=100mA		MAX	40	60	mA
I_L	I_G=1.2I_{GT}	Ⅰ-Ⅲ-Ⅳ	MAX	50	70	mA

		II		70	90	
dV/dt	V_D=2/3V_{DRM} T_j=125℃ Gate open		MIN	200	500	V/μs

STATIC CHARACTERISTICS

Symbol	Test Condition			Value	Unit
V_{TM}	I_{TM}=11A t_p=380μs	T_j=25℃	MAX	1.5	V
I_{DRM} I_{RRM}	V_{DRM}= V_{RRM}	T_j=25℃	MAX	5	μA
		T_j=125℃		1	mA

THERMAL RESISTANCES

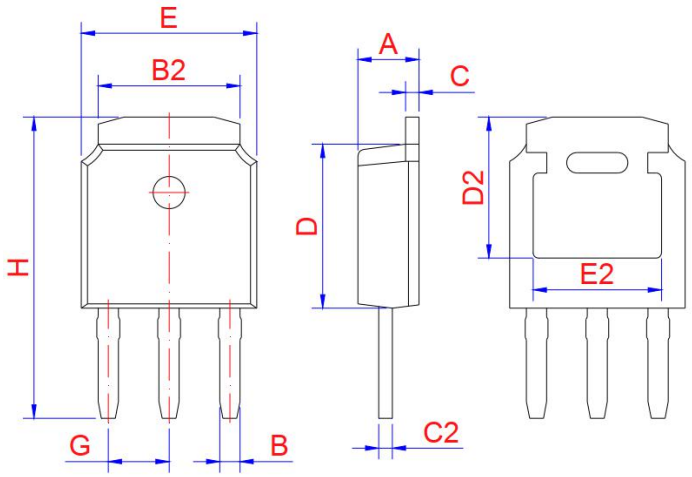
Symbol	Test Condition		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-251-4R/ TO-252-4R	2.0	℃/W
		TO-220A(Ins）	2.8	
		TO-220B(Non-Ins）	2.9	
		TO-220F(Ins）	3.1	
		TO-263	3.0	

ORDERING INFORMATION

BT A 08–600 CW

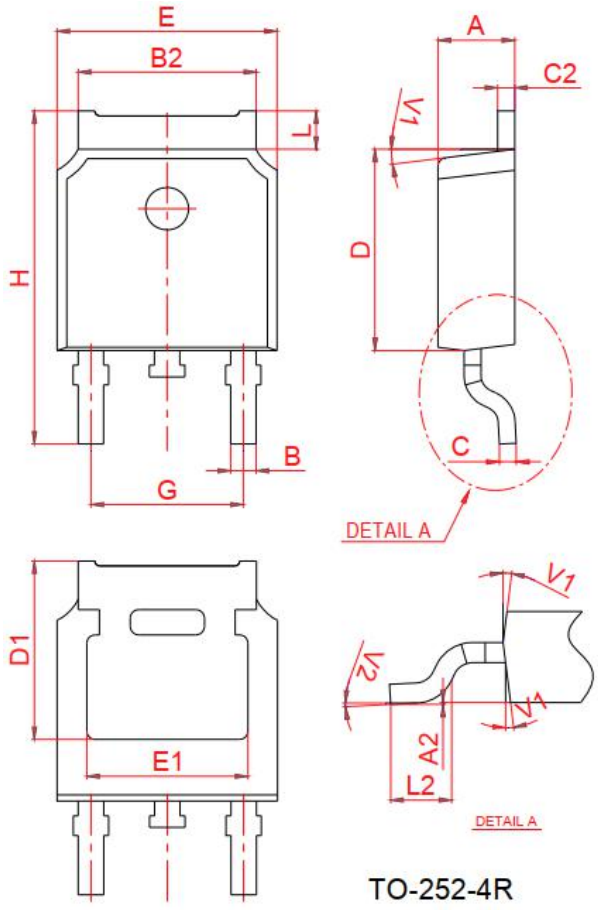
- BT: Triacs
- A: A:Insulated; B:Non-Insulated
- 08: $I_{T(RMS)}$:8A
- 600: V_{DRM}、V_{RRM}: 600：600V; 800：800V
- CW: B：I_{GT1-3}≤50mA、I_{GT4}≤100mA; C：I_{GT1-3}≤25mA、I_{GT4}≤50mA; TW：I_{GT1-3}≤5mA; SW：I_{GT1-3}≤10mA; CW：I_{GT1-3}≤35mA; BW：I_{GT1-3}≤50mA

PACKAGE MECHANICAL DATA



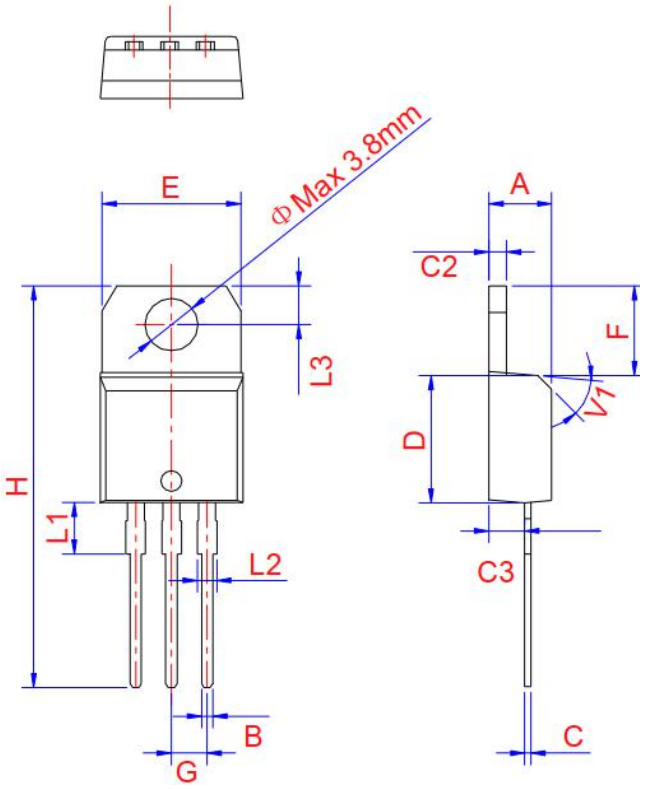
TO-251-4R

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10	2.30	2.50	0.083	0.091	0.098
B	0.66	0.76	0.86	0.026	0.030	0.034
B2	5.15	5.33	5.48	0.203	0.210	0.216
C	0.44	0.51	0.58	0.017	0.020	0.023
C2	0.44	0.51	0.58	0.017	0.020	0.023
D	5.90	6.10	6.30	0.232	0.240	0.248
D2	5.30REF			0.209REF		
E	6.40	6.60	6.80	0.252	0.260	0.268
E2	4.83REF			0.190REF		
G	2.19	2.29	2.39	0.086	0.090	0.094
H	10.60	11.20	11.80	0.417	0.441	0.465



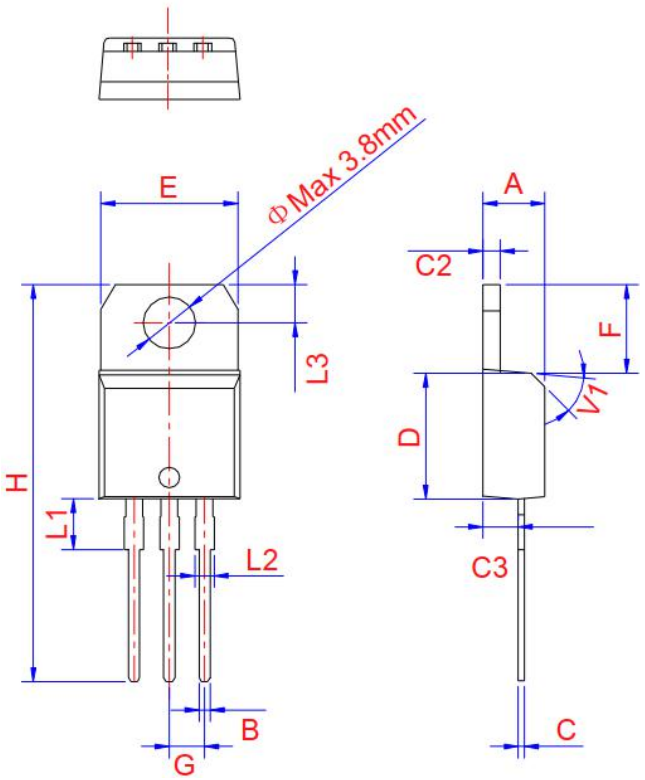
TO-252-4R

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.2		2.4	0.087		0.094
A2	0		0.1	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.1		5.46	0.201		0.215
C	0.46		0.58	0.018		0.023
C2	0.44		0.58	0.017		0.023
D	5.9		6.3	0.232		0.248
D1	5.30REF			0.211REF		
E	6.4		6.8	0.252		0.268
E1	4.63			0.182		
G	4.372		4.772	0.172		0.188
H	9.8		10.4	0.386		0.409
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°



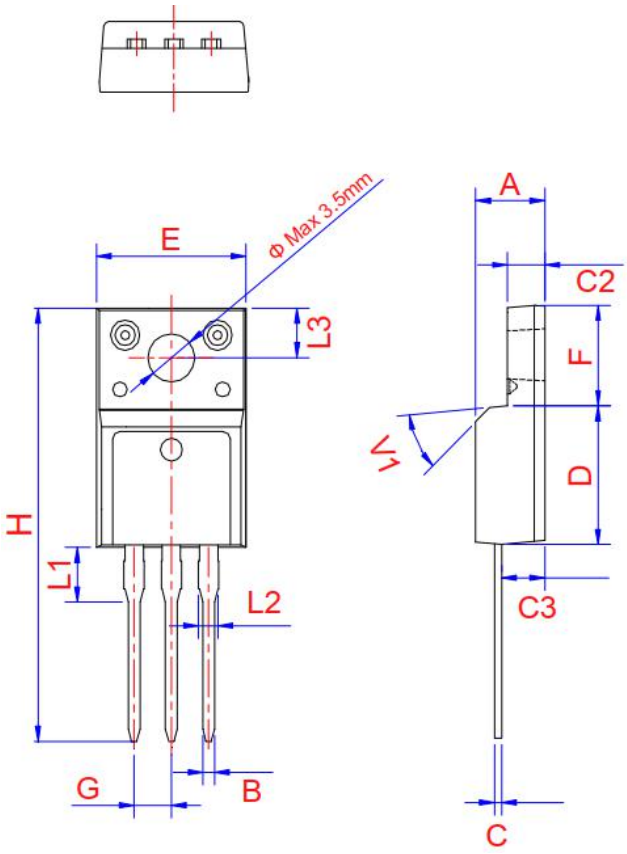
TO-220A Ins

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.4	4.47	4.6	0.173	0.176	0.181
B	0.61		0.88	0.024		0.035
C	0.46	0.50	0.7	0.018	0.02	0.028
C2	1.21	1.27	1.32	0.048	0.050	0.052
C3	2.4		2.72	0.094		0.107
D	8.6		9.7	0.339		0.382
E	9.8		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.7	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	



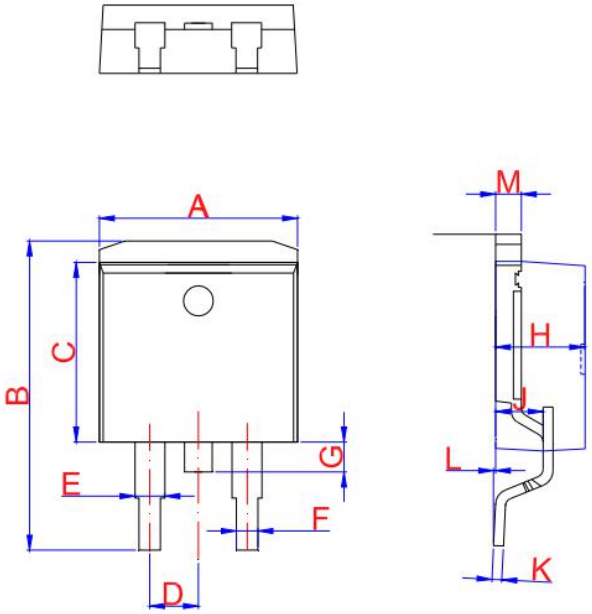
TO-220B Non-Ins

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.4	4.47	4.6	0.173	0.176	0.181
B	0.61		0.88	0.024		0.035
C	0.46	0.50	0.7	0.018	0.02	0.028
C2	1.21	1.27	1.32	0.048	0.050	0.052
C3	2.4		2.72	0.094		0.107
D	8.6		9.7	0.339		0.382
E	9.8		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.7	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	



TO-220F Ins

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.5		4.9	0.177		0.193
B	0.74	0.8	0.83	0.029	0.031	0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.6		3	0.102		0.118
D	8.8		9.3	0.346		0.366
E	9.8		10.4	0.386		0.41
F	6.4		6.8	0.252		0.268
G		2.54			0.1	
H	28		29.8	1.102		1.173
L1		3.63			0.148	
L2	1.14		1.7	0.045		0.067
L3	2.65	3.3	0		0.13	0.116
V1		45°			45°	



TO-263

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.9		10.3	0.390		0.406
B	14.7		15.8	0.579		0.622
C	8.5		8.9	0.370		0.378
D		2.54			0.100	
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.029		0.033
G			1.75			0.069
H	4.40	4.60	4.80	0.173	0.181	0.189
J	2.40	2.60	2.80	0.094	0.102	0.110
L	0	0.1	0.25	0	0.004	0.010
M	1.17	1.27	1.37	0.046	0.05	0.054

FIG.1: Maximum power dissipation versus RMS on-state current

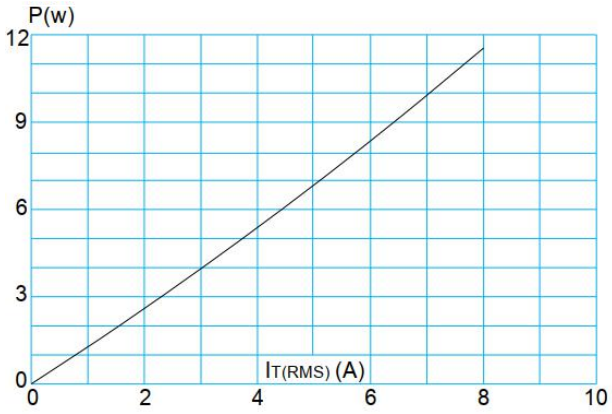


FIG.2: RMS on-state current versus case temperature

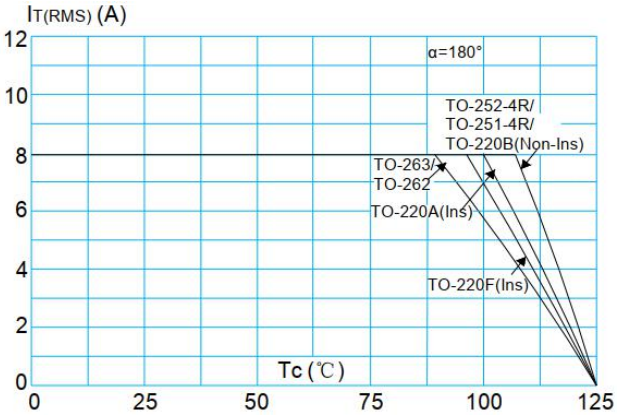


FIG.3: Surge peak on-state current versus number of cycles

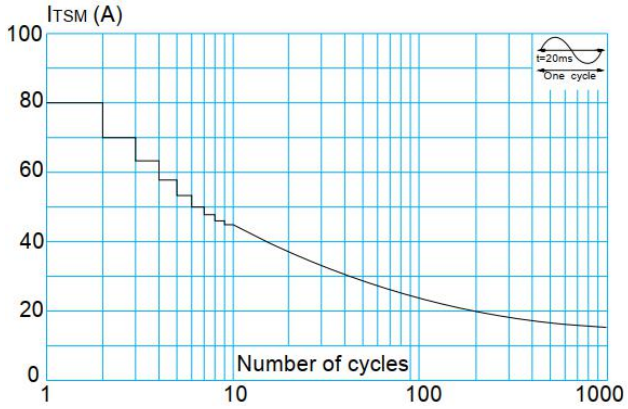


FIG.4: On-state characteristics (maximum values)

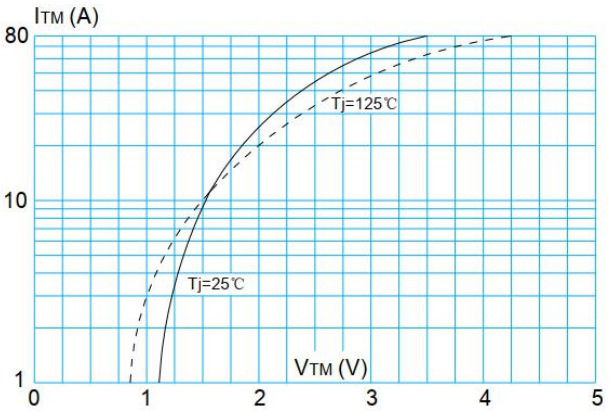


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<20ms, and corresponging value of I^2t (Ⅰ-Ⅱ-Ⅲ:dI/dt < 50A/μs;Ⅳ:dI/dt < 10A/μs)

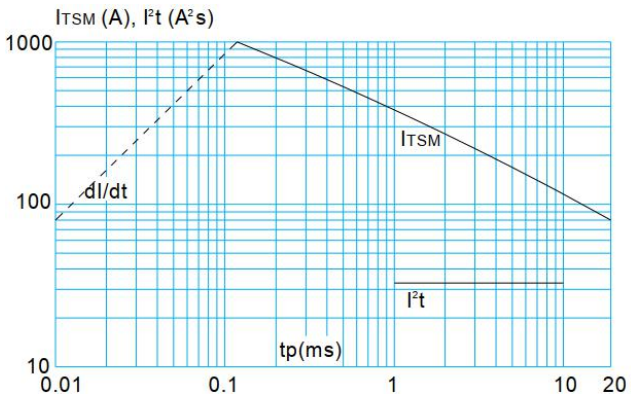


FIG.6: Relative variations of gate trigger current,holding current and latching current versus junction temperature